

Contents

<i>Preface to Fourth Edition</i>	(vii)
<i>Symbols</i>	(xvii)
<i>Brief History of Electronics</i>	(xxi)

Chapter 1

PN Junction Diode and its Applications	1-90
1.1 Review of Semiconductor Physics	2
1.1.1 Energy Levels and Energy Bands	2
1.1.2 The Bohr Atom	4
1.1.3 Effective Mass.....	4
1.1.4 Atomic Energy Levels.....	7
1.1.5 Photon Nature of Light.....	8
1.1.6 Ionization Potential	9
1.1.7 Collisions of Electrons with Atoms.....	9
1.1.8 Metastable States.....	12
1.1.9 Wave Properties of Matter	12
1.1.10 Schrodinger Equation.....	12
1.1.11 Wave Function	14
1.1.12 Electronic Configuration.....	15
1.1.13 Types of Electron Emission	16
1.2 n-Type and p-Type Semiconductors.....	23
1.2.1 n-Type or Donor Type Semiconductors.....	23
1.2.2 p-Type or Acceptor Type Semiconductors	23
1.3 Mass Action Law.....	24
1.4 Continuity Equation.....	24
1.5 The Hall Effect	26
1.6 Fermi Level in Intrinsic and Extrinsic Semiconductors	29
1.6.1 Fermi Level	29
1.6.2 The Intrinsic Concentration.....	30
1.6.3 Carrier Concentrations in a Semiconductor	30
1.6.4 Fermi Level in Intrinsic Semiconductor.....	31
1.7 p-n Diode Equation.....	33
1.8 Volt-Ampere (V-I) Characteristics	35

1.9	Temperature Dependence of V-I Characteristics.....	36
1.10	Ideal Vs Practical.....	40
1.11	Diode Equivalent Circuits.....	42
1.12	Break Down Mechanisms in Semiconductor Diodes	44
1.12.1	Avalanche Breakdown	44
1.12.2	Zener Breakdown	44
1.12.3	Thermal Breakdown.....	44
1.13	Zener Diode Characteristics	45
1.14	p-n Junction Diode as Rectifier	46
1.15	Half-Wave Rectifier.....	46
1.15.1	Maximum or Peak Current.....	47
1.15.2	Reading of D.C. Ammeter.....	47
1.15.3	Reading of A.C. Ammeter.....	48
1.15.4	Peak Inverse Voltage.....	48
1.15.5	Regulation	50
1.15.6	Ripple Factor.....	52
1.15.7	Ratio of Rectification (η)	54
1.15.8	Transformer Utilization Factor.....	55
1.15.9	Disadvantages of Half Wave Rectifier.....	56
1.15.10	Power Supply Specifications.....	56
1.16	Ripple Factor	56
1.17	Full Wave Rectifier (FWR).....	58
1.17.1	Ripple Factor.....	60
1.17.2	Regulation for FWR.....	60
1.17.3	Ratio of Rectification	61
1.17.4	Transformer Utilization Factor	62
1.17.5	Peak Inverse Voltage for Full Wave Rectifier	62
1.17.6	D.C. Saturation.....	62
1.18	Bridge Rectifiers.....	63
1.18.1	Advantages of Bridge Rectifier.....	63
1.18.2	Disadvantages	63
1.19	The Harmonic Components in Rectifier Circuit.....	64

1.20 Inductor Filter	65
1.20.1 Ripple Factor	66
1.20.2 Regulation	67
1.21 L-Section Filter	69
1.21.1 Ripple Factor in LC Filter	70
1.21.2 Bleeder Resistance	71
1.21.3 Swinging Choke	72
1.22 π -Section Filter	74
1.22.1 π -Section Filter with a Resistor Replacing the Inductor	74
1.22.2 Expression for Ripple Factor of π -Section Filter	75
1.23 Use of Zener Diode as Regulator	78
1.23.1 Zener Voltage Regulator Circuit	80
1.23.2 Shunt Regulator	80
<i>Summary</i>	84
<i>Objective Type Questions</i>	85
<i>Essay Type Questions</i>	86
<i>Multiple Choice Questions</i>	87
<i>Conceptual Questions (Interview Questions)</i>	89

Chapter 2

Transistor and FET Characteristics	91-134
2.1 Transistor Construction	92
2.1.1 Grown Type	92
2.1.2 Alloy Type	92
2.1.3 Manufacture of Grown Junction Transistor	92
2.1.4 Diffusion Type of Transistor Construction	93
2.1.5 Epitaxial Type	93
2.2 Bipolar Junction Transistor (BJT)	93
2.3 Transistor as an Amplifier	94
2.4 Types of Transistor Configurations	95
2.4.1 Common Base Configuration (C.B)	95
2.4.2 Common Emitter Configuration (C.E)	97
2.4.3 Common Collector Configuration (C.C)	103
2.5 Limits of Operation	105

2.6	BJT Specifications.....	107
2.7	The Junction Field Effect Transistor (FET or JFET).....	108
2.7.1	JFET	108
2.7.2	n-Channel JFET	109
2.7.3	p-Channel JEET	109
2.7.4	FET Structure	110
2.7.5	FET Operation.....	110
2.7.6	Pinch off Region.....	114
2.8	JFET Volt-Ampere Characteristics.....	115
2.9	FET as a Voltage Variable Resistor.....	118
2.10	Comparison between BJT and FET	118
2.11	MOSFET	119
2.11.1	Depletion MOSFET	120
2.11.2	Enhancement MOSFET	123
2.11.3	MOSFET Operation	125
2.11.4	MOSFET Characteristics	126
	<i>Summary</i>	129
	<i>Objective Type Questions</i>	130
	<i>Essay Type Questions</i>	131
	<i>Multiple Choice Questions</i>	131

Chapter 3

 Biasing and Stabilization	135-168	
3.1	Operating Point.....	136
3.2	DC and AC Load Lines	138
3.3	Need for Biasing/Importance of Biasing	138
3.4	Fixed Bias Circuit or (Base Bias Circuit)	139
3.5	Collector to Base Bias circuit	140
3.6	Self Bias or Emitter Bias Circuit	142
3.7	Bias Stability.....	143
3.8	Stabilization Against Variations in I_{CO} and V_{BE} and β	144

3.9 Bias Compensation	145
3.9.1 Diode Compensation for V_{BE}	147
3.10 Thermal Runaway	147
3.11 Condition for Thermal Stability in CE Configuration	154
3.11.1 Derivation for Condition for Thermal Stability for CE Configuration	154
3.12 Biasing of FET	156
3.12.1 Fixed Bias Circuit	157
3.12.2 Self Bias Circuit	158
3.12.3 Self Bias with External Voltage	159
3.12.4 Source Self Bias	160
3.13 Biasing of Zero Current Drift	160
3.14 Biasing Against Device Variation	162
<i>Summary</i>	164
<i>Objective Type Questions</i>	165
<i>Essay Type Questions</i>	165
<i>Multiple Choice Questions</i>	166
<i>Conceptual Questions (Interview Questions)</i>	167

Chapter 4

Small Signal Analysis of FET and BJT Amplifiers	169-198
4.1 BJT Modeling using h-parameters	170
4.2 Determination of h-Parameters from Transistor Characteristics	170
4.3 Measurement of h-Parameters	171
4.4 Analysis of CE, CB and CC Configurations using h-Parameters	173
4.4.1 Input Impedance (Z_i)	174
4.4.2 Voltage Gain (A_V)	175
4.4.3 Output Admittance (Y_o)	175
4.4.4 Voltage Gain (A_{V_S}) Considering Source Resistance (R_S)	176
4.4.5 Current Gain (A_{I_S}) Considering Source Resistance	176
4.4.6 Power Gain (A_p)	177
4.5 Comparison of CE, CB, CC Configurations using h-parameters	178
4.6 Simplified Transistor Hybrid Model	180

4.7	Miller's Theorem.....	182
4.7.1	Dual of Miller's Theorem	183
4.8	Small Signal Model of JFET	185
4.9	Small Signal Model of MOSFET Amplifiers.....	186
4.10	Small Signal Analysis of Common Source JFET Amplifier	188
4.11	Small Signal Analysis of Common Drain FET Amplifier.....	190
	<i>Summary</i>	193
	<i>Objective Type Questions</i>	193
	<i>Essay Type Questions</i>	194
	<i>Multiple Choice Questions</i>	195
	<i>Conceptual Questions (Interview Questions)</i>	197

Chapter 5

	Special Purpose Electronic Devices	199-228
5.1	The Tunnel Diode.....	200
5.1.1	Principle of Operation.....	200
5.1.2	Characteristics of a Tunnel Diode.....	201
5.2	Varactor Diode	203
5.3	Schottky Barrier Diode.....	204
5.4	Silicon Controlled Rectifier.....	207
5.4.1	Annular Type of Construction of SCR.....	207
5.4.2	Static Characteristics	208
5.4.3	Analysis of the Operation of SCR.....	209
5.4.4	Anode to Cathode Voltage - Current Characteristics.....	212
5.5	DIAC	213
5.5.1	Diagram for Basic Construction and Symbol.....	213
5.5.2	Characteristics of DIAC	213
5.6	TRIAC	214
5.6.1	Construction	215
5.6.2	Characteristics	215
5.7	Unijunction Transistor (UJT)	215
5.7.1	UJT Construction and Operation.....	216
5.7.2	V - I Characteristics of UJT	218
5.7.3	Applications of UJT	219

5.8	Semiconductor Photo Devices	219
5.8.1	Light Dependent Resistors (LDR).....	219
5.8.2	Light Emitting Diode (LED).....	221
5.8.3	Photo Diodes	225
5.8.4	Photo Transistors.....	226
	<i>Summary</i>	227
	<i>Essay Type Questions</i>	227
	<i>Multiple Choice Questions</i>	227
	<i>Conceptual Questions (Interview Questions)</i>	228

Chapter 6

Feedback Amplifiers

6.1	Feedback Amplifiers.....	230
6.2	Classification of Amplifiers	230
6.2.1	Voltage Amplifier	231
6.2.2	Current Amplifier	231
6.2.3	Transconductance Amplifier.....	232
6.2.4	Trans Resistance Amplifier	232
6.3	Feedback Concept	233
6.4	Types of Feedback.....	235
6.5	Effect of Negative Feedback on Transfer Gain	235
6.5.1	Reduction in Gain	236
6.5.2	Increase in Bandwidth.....	236
6.5.3	Reduction in Distortion	237
6.5.4	Feedback to Improve Sensitivity.....	238
6.5.5	Frequency Distortion	238
6.5.6	Band Width	239
6.5.7	Sensitivity of Transistor Gain	239
6.5.8	Reduction of Nonlinear Distortion	240
6.5.9	Reduction of Noise	240
6.6	Transfer Gain with feedback	240
6.6.1	Loop Gain.....	242
6.7	Classification of Feedback Amplifiers	244

6.8	Effect of Feedback on Input Resistance	245
6.8.1	Input Resistance with Shunt Feedback.....	245
6.8.2	Input Impedance with Series Feedback.....	247
6.9	Effect of Negative Feedback on R_o	248
6.9.1	Voltage Series Feedback	248
6.9.2	Current Shunt Feedback.....	249
6.10	Analysis of Feedback Amplifiers	254
6.10.1	Voltage Series Feedback	254
6.10.2	Current Shunt Feedback.....	259
6.10.3	Current Series Feedback.....	265
6.10.4	Current Series Feedback (Trans Conductance Amplifier)	266
6.10.5	Voltage Shunt Feedback (Trans Resistance Amplifier)	269
	<i>Summary</i>	273
	<i>Objective Type Questions</i>	273
	<i>Essay Type Questions</i>	274
	<i>Multiple Choice Questions</i>	275
	<i>Conceptual Questions (Interview Questions)</i>	276

Chapter 7

Oscillators

7.1	Oscillators.....	278
7.1.1	Performance Measures of Oscillator Circuits	278
7.2	Sinusoidal Oscillators	281
7.3	Barkhausen Criterion	281
7.4	R – C Phase-shift Oscillator (using JFET).....	282
7.4.1	To find the β of the RC Phase-shift Network (JFET)	283
7.5	Transistor RC Phase-shift Oscillator	285
7.6	A General form of LC Oscillator Circuit	288
7.7	Loop Gain	288
7.7.1	For Hartley Oscillator	290
7.7.2	For Colpitts Oscillator.....	290
7.8	Wien Bridge Oscillator	291
7.9	Expression for f	292
7.10	Thermistor	293

7.11 Sensistor.....	293
7.12 Amplitude Stabilization.....	293
7.13 Applications	294
7.14 Resonant Circuit Oscillators.....	294
7.15 Crystal Oscillators	295
7.16 Frequency Stability	296
7.17 Frequency of Oscillations for Parallel Resonance Circuit	297
7.18 1 MHz FET Crystal Oscillator Circuit.....	297
<i>Summary</i>	299
<i>Objective Type Questions</i>	299
<i>Essay Type Questions</i>	300
<i>Multiple Choice Questions</i>	301
<i>Conceptual Questions (Interview Questions)</i>	302
<i>Additional Objective Type Questions (Chapter 1-7)</i>	303
<i>Answers to Additional Objective Type Questions</i>	304
<i>Appendices</i>	305
<i>Appendix-I Colour Codes for Electronic Components</i>	306
<i>Appendix-II Resistor and Capacitor Values</i>	309
<i>Appendix-III Capacitors</i>	312
<i>Appendix-IV Inductors</i>	318
<i>Appendix-V Miscellaneous</i>	322
<i>Appendix-VI Circuit Symbols</i>	332
<i>Appendix-VII Unit Conversion Factors</i>	334
<i>Appendix-VIII American Wire Gauge Sizes and Metric Equivalents</i>	337
<i>Answers to Objective Type and Multiple Choice Questions</i>	339
<i>MCQs from Gate Examination, Yearwise from 1996 to 2012</i>	347
<i>Index</i>	387